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


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Substitute for form 1449A/B/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)				Complete if Known	
				Application Number	10/779,557
				Filing Date	February 6, 2004
				First Named Inventor	Franz Hofmann
				Art Unit	MA 2822
				Examiner Name	Not Yet Assigned Soward
Sheet	1	of	1	Attorney Docket Number	20046/0200847-USO

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
	AA	US-6,335,554-B1	01-01-2002	Yoshikawa	
	AB	US-6,388,293-B1	05-14-2002	Ogura et al.	

FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ³
		Country Code ⁴ -Number ⁵ -Kind Code ⁶ (if known)	MM-DD-YYYY			
	BA	DE-100 36 911-A1	02-14-2002	Hofmann, Franz et al.		X
	BB	JP-2001 156188-A1	06-08-2001	Yoshikawa Kuniyoshi		X

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NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			T ²
	CA	Hayashi Y et al.: "Twin Monos Cell With Dual Control Gates"; 2000 Symposium on VLSI TECHNOLOGY, Digest of Technical Papers, Honolulu, HI, June 13-15, 2000, Symposium on VLSI Technology, New York, NY; IEEE, US, 13 June 2000, pages 122-123, XP000970787.			
	CB	PATENT ABSTRACTS OF JAPAN, vol. 2000, no. 22, 9 March 2001 & JP 2001 148434 A (New Heiro: KK; Halo LSI Design & Device Technol Inc), 29 May 2001, abstract.			
	CC	Naruke K et al: "A New Flash-Erase EEPROM Cell with a Sidewall Select-Gate on Its Source Side"; Tech. Digest, 1989, IEDM 89-603, pages 25.7.1 - 25.7.4.			

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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Examiner Signature		Date Considered	5-19-05
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